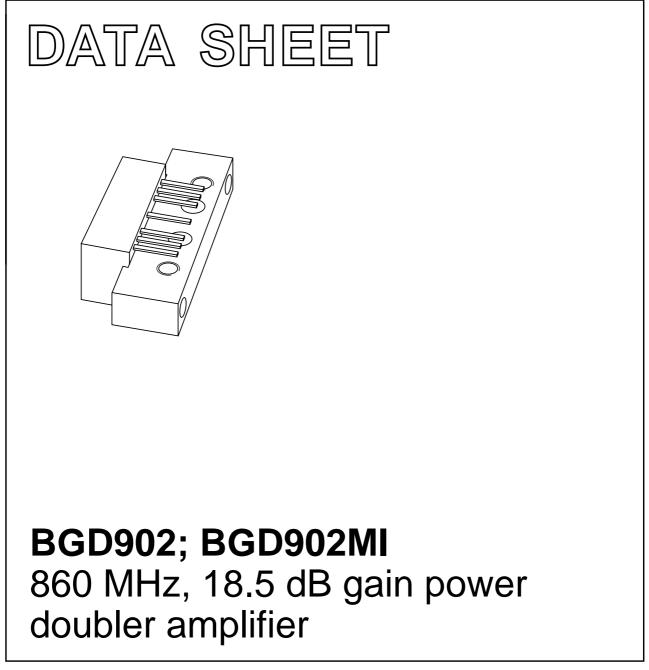
# DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Mar 29 2001 Nov 02



### FEATURES

- Excellent linearity
- Extremely low noise
- Excellent return loss properties
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

### APPLICATIONS

• CATV systems operating in the 40 to 900 MHz frequency range.

#### DESCRIPTION

Hybrid amplifier modules in a SOT115J package operating with a voltage supply of 24 V (DC).

Both modules are electrically identical only the pinning is different.

### BGD902; BGD902MI

#### **PINNING - SOT115J**

PIN	DESCRIPTION		
	BGD902	BGD902MI	
1	input	output	
2, 3	common	common	
5	+V <sub>B</sub>	+V <sub>B</sub>	
7, 8	common	common	
9	output	input	

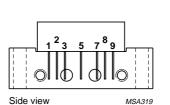


Fig.1 Simplified outline.

### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	18.2	18.8	dB
		f = 900 MHz	19	20	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	405	435	mA

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER		MAX.	UNIT
V <sub>B</sub>	supply voltage		30	V
Vi	RF input voltage		70	dBmV
T <sub>stg</sub>	storage temperature		+100	°C
T <sub>mb</sub>	operating mounting base temperature		+100	°C

# BGD902; BGD902MI

### CHARACTERISTICS

### Bandwidth 40 to 900 MHz; V\_B = 24 V; T\_mb = 35 °C; Z\_S = Z\_L = 75 $\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	18.2	18.5	18.8	dB
		f = 900 MHz	19	19.5	20	dB
SL	slope cable equivalent	f = 40 to 900 MHz		0.9	1.4	dB
FL	flatness of frequency response	f = 40 to 900 MHz	-	±0.15	±0.3	dB
s <sub>11</sub>	input return losses	f = 40 to 80 MHz	21	24	-	dB
		f = 80 to 160 MHz	22	26	-	dB
		f = 160 to 320 MHz	22	28	-	dB
		f = 320 to 640 MHz	19	22	-	dB
		f = 640 to 900 MHz	18	21	-	dB
\$ <sub>22</sub>	output return losses	f = 40 to 80 MHz	25	32	-	dB
		f = 80 to 160 MHz	25	33	-	dB
		f = 160 to 320 MHz	21	29	-	dB
		f = 320 to 750 MHz	20	25	-	dB
		f = 750 to 900 MHz	19	22	-	dB
s <sub>21</sub>	phase response	f = 50 MHz	-45	_	+45	deg
СТВ	composite triple beat	49 chs flat; V <sub>o</sub> = 47 dBmV; f <sub>m</sub> = 859.25 MHz	-	-68.5	-67	dB
		77 chs flat; $V_0 = 44 \text{ dBmV}$ ; $f_m = 547.25 \text{ MHz}$	_	-70	-68	dB
		110 chs flat; $V_0 = 44 \text{ dBmV}$ ; $f_m = 745.25 \text{ MHz}$	-	-63.5	-62	dB
		129 chs flat; $V_0 = 44 \text{ dBmV}$ ; $f_m = 859.25 \text{ MHz}$	-	-60	-58	dB
		110 chs; $f_m = 400$ MHz; V <sub>o</sub> = 49 dBmV at 550 MHz; note 1	-	-64	-62	dB
		129 chs; $f_m = 650$ MHz; V <sub>o</sub> = 49.5 dBmV at 860 MHz; note 2	-	-58.5	-56.5	dB
X <sub>mod</sub>	cross modulation	49 chs flat; $V_0 = 47 \text{ dBmV}$ ; $f_m = 55.25 \text{ MHz}$	_	-66.5	-64	dB
		77 chs flat; $V_o = 44 \text{ dBmV}$ ; $f_m = 55.25 \text{ MHz}$	_	-69.5	-67	dB
		110 chs flat; V <sub>o</sub> = 44 dBmV; f <sub>m</sub> = 55.25 MHz	_	-66	-63.5	dB
		129 chs flat; V <sub>o</sub> = 44 dBmV; f <sub>m</sub> = 55.25 MHz	-	-64.5	-62	dB
		110 chs; $f_m = 400$ MHz; V <sub>o</sub> = 49 dBmV at 550 MHz; note 1	-	-63	-60	dB
		129 chs; $f_m = 860$ MHz; V <sub>o</sub> = 49.5 dBmV at 860 MHz; note 2	-	-61	-58	dB
CSO	composite second order distortion	49 chs flat; $V_0 = 47$ dBmV; $f_m = 860.5$ MHz	-	-65	-62	dB
		77 chs flat; $V_o = 44 \text{ dBmV}$ ; $f_m = 548.5 \text{ MHz}$	-	-72	-67	dB
		110 chs flat; $V_0 = 44 \text{ dBmV}$ ; $f_m = 746.5 \text{ MHz}$	-	-65	-60	dB
		129 chs flat; $V_0 = 44 \text{ dBmV}$ ; $f_m = 860.5 \text{ MHz}$	-	-61	-58	dB
		110 chs; $f_m = 250$ MHz; V <sub>o</sub> = 49 dBmV at 550 MHz; note 1	-	-67	-63	dB
		129 chs; $f_m = 250 \text{ MHz}$ ; V <sub>o</sub> = 49.5 dBmV at 860 MHz; note 2	-	-62	-58	dB

### BGD902; BGD902MI

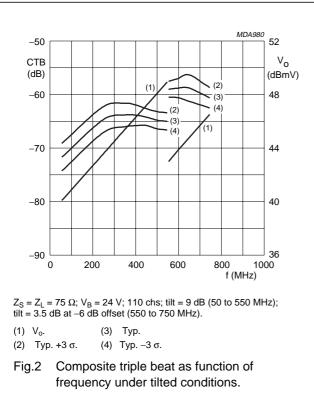
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
d <sub>2</sub>	second order distortion	note 3	-	-80	-74	dB
		note 4	-	-83	-77	dB
		note 5	-	-84	-78	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 6	64.5	66	-	dBmV
		d <sub>im</sub> = -60 dB; note 7	65.5	67	-	dBmV
		d <sub>im</sub> = -60 dB; note 8	67.5	69	-	dBmV
		CTB compression = 1 dB; 129 chs flat; f = 859.25 MHz	48.5	49.5	-	dBmV
		CSO compression = 1 dB; 129 chs flat; f = 860.5 MHz	50	53	-	dBmV
F	noise figure	f = 50 MHz	-	4.5	5	dB
		f = 550 MHz	-	5	5.5	dB
		f = 750 MHz	-	5.5	6.5	dB
		f = 900 MHz	_	6.5	8	dB
I <sub>tot</sub>	total current consumption (DC)	note 9	405	420	435	mA

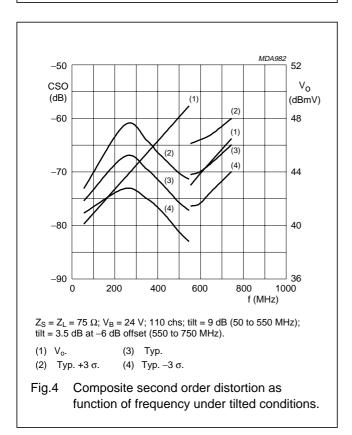
#### Notes

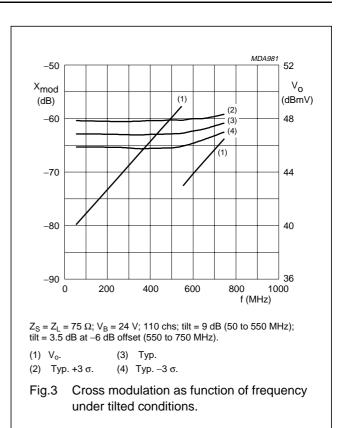
- 1. Tilt = 9 dB (50 to 550 MHz); tilt = 3.5 dB at -6 dB offset (550 to 750 MHz).
- 2. Tilt = 12.5 dB (50 to 860 MHz).
- 3.  $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$  $f_q = 805.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at  $f_p + f_q = 860.5 \text{ MHz}.$
- 4.  $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$  $f_q = 691.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at  $f_p + f_q = 746.5 \text{ MHz}.$
- 5.  $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$  $f_q = 493.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at  $f_p + f_q = 548.5 \text{ MHz}.$
- 6. Measured according to DIN45004B:  $f_p = 851.25 \text{ MHz}; V_p = V_o;$   $f_q = 858.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$   $f_r = 860.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$ measured at  $f_p + f_q - f_r = 849.25 \text{ MHz}.$
- 7. Measured according to DIN45004B:  $f_p = 740.25 \text{ MHz}; V_p = V_0;$   $f_q = 747.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$   $f_r = 749.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$ measured at  $f_p + f_q - f_r = 738.25 \text{ MHz}.$
- $\frac{1}{10} = \frac{1}{10} = \frac{1}{10}$
- 8. Measured according to DIN45004B:  $f_p = 540.25 \text{ MHz}; V_p = V_0;$   $f_q = 547.25 \text{ MHz}; V_q = V_0 - 6 \text{ dB};$   $f_r = 549.25 \text{ MHz}; V_r = V_0 - 6 \text{ dB};$ measured at  $f_p + f_q - f_r = 538.25 \text{ MHz}.$
- 9. The module normally operates at  $V_B = 24$  V, but is able to withstand supply transients up to 35 V.

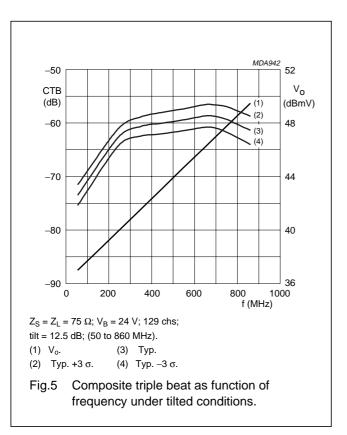
BGD902; BGD902MI

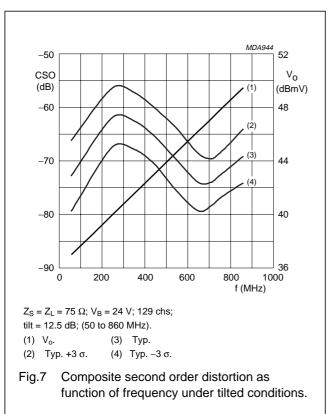
# 860 MHz, 18.5 dB gain power doubler amplifier



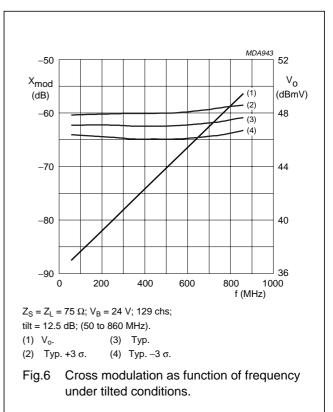




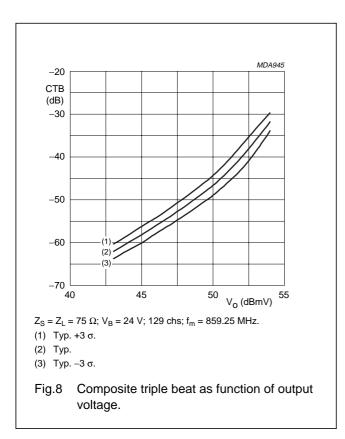


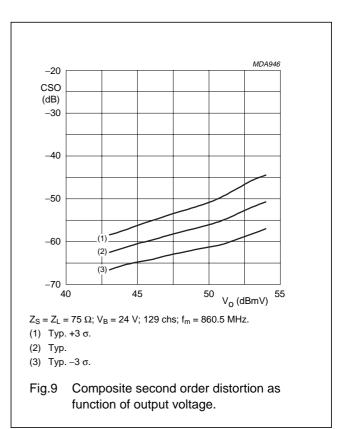


# BGD902; BGD902MI



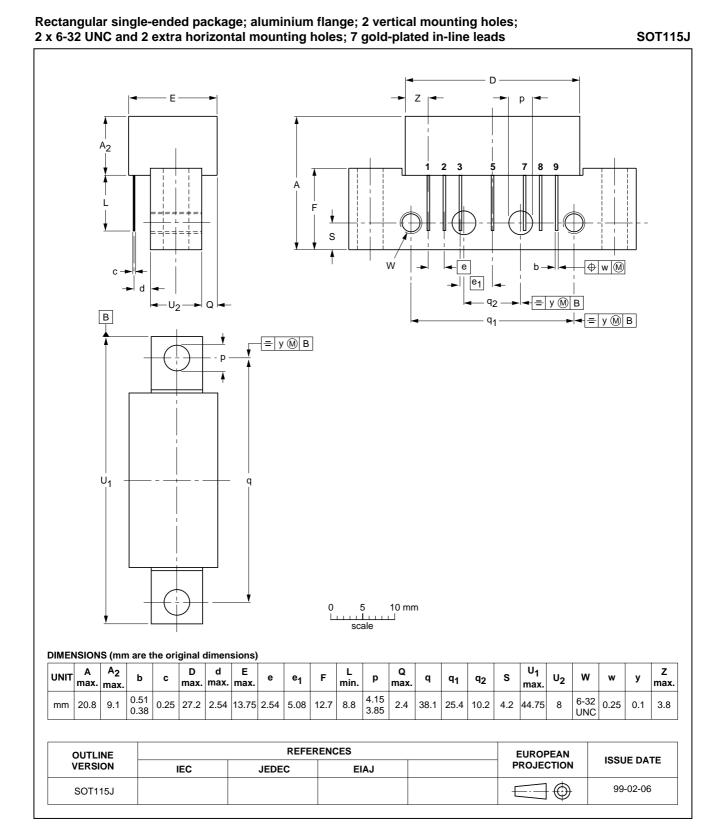
### BGD902; BGD902MI





### BGD902; BGD902MI

### PACKAGE OUTLINE



### BGD902; BGD902MI

#### DATA SHEET STATUS

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Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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